NSN 5962-01-420-6425

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View Online at https://aerobasegroup.com/nsn/5962-01-420-6425

Body Length:
1.290 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
0.225 inches
Maximum Power Dissipation Rating:
1.04 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Pacer dawn
Features Provided:
Bipolar and burn in, mil-std-883, class b and electrostatic sensitive and monolithic and programmed and tested to mil-std-883
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Criticality Code Justification:
Cbbl
Case Outline Source And Designator:
D-3 mil-m-38510
Current Rating Per Characteristic:
190.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, programmed (prom 93z565a and 93z665a)
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 7.0 volts power source and 5.5 volts input
Capitance Rating Per Characteristic:
10.00 input picofarads and 15.00 output picofarads
Time Rating Per Chacteristic:
100.00 nanoseconds propagation delay and 100.00 nanoseconds access

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Memory Device Type:

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Special	Features:
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Altered item programmed using 14933 8200902ja (which is 81349 m38510/21202bja)

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A458a0